LM4864 725mW Audio Power Amplifier with Shutdown Mode



# LM4864 Boomer® Audio Power Amplifier Series 725mW Audio Power Amplifier with Shutdown Mode

## **General Description**

The LM4864 is a bridged audio power amplifier capable of delivering 725mW of continuous average power into an  $8\Omega$ load with 1% THD+N from a 5V power supply.

Boomer<sup>®</sup> audio power amplifiers were designed specifically to provide high quality output power from a low supply voltage while requiring a minimal amount of external components. Since the LM4864 does not require output coupling capacitors, bootstrap capacitors or snubber networks, it is optimally suited for low-power portable applications.

The LM4864 features an externally controlled, low power consumption shutdown mode, and thermal shutdown protection.

The closed loop response of the unity-gain stable LM4864 can be configured by external gain-setting resistors. The device is available in multiple package types to suit various applications.

# **Key Specifications**

 $\blacksquare$  P<sub>O</sub> at 1% THD+N with V<sub>DD</sub> = 5V, 1kHz

-	
LM4864LD, $4\Omega$ load	625mW (typ)
LM4864LD, $8\Omega$ load	725mW (typ)

# **Typical Application**

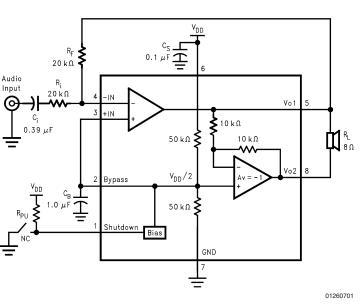


FIGURE 1. Typical Audio Amplifier Application Circuit

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LM4864M & LM4864Ν <sup>*</sup> , 8Ω load	675mW (typ)
LM4864MM, 8 $\Omega$ load (Note 10)	300mW (typ)
LM4864, 16Ω load	550mW (typ)
Shutdown current	0.7µA (typ)

\* Not recommended for new designs. Contact NSC Audio Marketing.

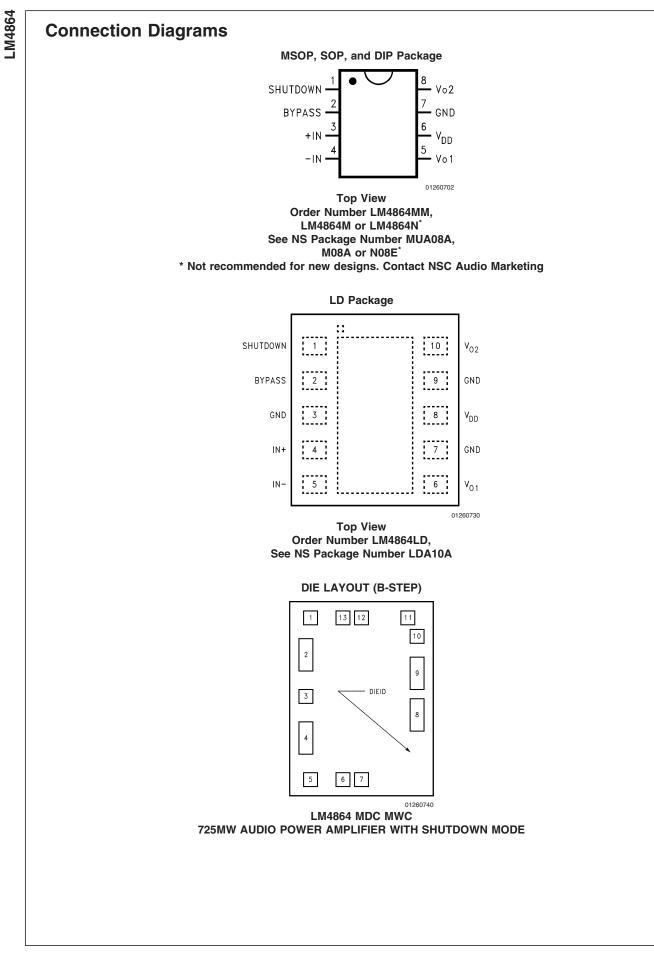
## Features

- MSOP, SOP, DIP<sup>\*</sup>, and LD packaging
- No output coupling capacitors, bootstrap capacitors, or snubber circuits are necessary
- Thermal shutdown protection circuitry
- Unity-gain stable
- External gain configuration capability

\* Not recommended for new designs. Contact NSC Audio Marketing.

## Applications

- Cellular phones
- Personal computers
- General purpose audio



## Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	6.0V		
Storage Temperature	−65°C to +150°C		
Input Voltage	–0.3V to V <sub>DD</sub> + 0.3V		
Power Dissipation (Note 3)	Internally limited		
ESD Susceptibility (Note 4)	2000V		
ESD Susceptibility (Note 5) 200			
Junction Temperature 150°			
Soldering Information			
Small Outline Package			
Vapor Phase (60 sec.)	215°C		
Infrared (15 sec.)	220°C		
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See AN-450 "Surface Mounting and their Effects on

Product Reliability" for other methods of soldering surface mount devices.

\* Not recommended for new designs. Contact NSC Audio Marketing.

## **Operating Ratings**

Thermal Resistance

 $\theta_{JC}$  (MSOP)

 $\theta_{JA}$  (MSOP)

 $\theta_{JC}$  (SOP)

Temperature Range	
$T_{MIN} \leq T_{A} \leq T_{MAX}$	$-40^{\circ}C \le T_A \le$
	+85°C
Supply Voltage	$2.7V \le V_{\text{DD}} \le 5.5V$

## Electrical Characteristics V<sub>DD</sub> = 5V (Note 1) (Note 2)

The following specifications apply for  $V_{DD}$  = 5V, for all available packages, unless otherwise specified. Limits apply for  $T_A$  = 25°C

			LM4	LM4864		
Symbol	Parameter	Conditions	Typical (Note 6)	Limit (Notes 7, 8)	Units (Limits)	
I <sub>DD</sub>	Quiescent Power Supply Current	$V_{IN} = 0V, I_O = 0A$ (Note 9)	3.6	6.0	mA (max)	
I <sub>SD</sub>	Shutdown Current	$V_{PIN1} = V_{DD}$	0.7	5	µA (max)	
V <sub>os</sub>	Output Offset Voltage	$V_{IN} = 0V$	5	50	mV (max)	
Po	Output Power	THD = 1% (max); f = 1 kHz; $R_L = 4\Omega$ ; LM4864LD (Note 11)	625		mW (min)	
		THD = 1% (max); f = 1 kHz; R <sub>L</sub> = 8Ω; LM4864LD (Note 11)	725		mW (min)	
		THD = 1% (max); f = 1 kHz; $R_L = 8\Omega$ ; LM4864MM (Note 10)		300	mW (min)	
		THD = 1% (max); f = 1 kHz; $R_{L} = 8\Omega$ ; LM4864M and LM4864N <sup>*</sup>	675	300	mW (min)	
		THD+N = 1%; f = 1 kHz; $R_{L} = 16\Omega$ ;	550		mW	
THD+N	Total Harmonic Distortion+Noise	$\label{eq:PO} \begin{array}{l} P_{O} = 300 \text{ mWrms}; \ A_{VD} = 2; \ R_{L} = 8\Omega; \\ 20 \text{ Hz} \leq f \leq 20 \text{ kHz}, \ BW < 80 \text{kHz} \end{array}$	0.7		%	
PSRR	Power Supply Rejection Ratio	$V_{DD} = 4.9V - 5.1V$	50	1	dB	

\* Not recommended for new designs. Contact NSC Audio Marketing.

## Electrical Characteristics V<sub>DD</sub> = 3V (Note 1) (Note 2)

The following specifications apply for  $V_{DD}$  = 3V, for all available packages, unless otherwise specified. Limits apply for  $T_A$  = 25°C

			LM4864		
Symbol	Parameter	Conditions	<b>Typical</b> (Note 6)	Limit (Notes 7, 8)	Units (Limits)
I <sub>DD</sub>	Quiescent Power Supply Current	$V_{IN} = 0V, I_O = 0A \text{ (Note 9)}$	1.0	3.0	mA (max)
I <sub>SD</sub>	Shutdown Current	$V_{PIN1} = V_{DD}$	0.3	2.0	µA (max)

56° C/W

210°C/W

35°C/W

## Electrical Characteristics V<sub>DD</sub> = 3V (Note 1) (Note 2) (Continued)

The following specifications apply for  $V_{DD}$  = 3V, for all available packages, unless otherwise specified. Limits apply for  $T_A$  = 25°C

			LM4864		
Symbol	Parameter	Conditions	<b>Typical</b> (Note 6)	Limit (Notes 7, 8)	Units (Limits)
V <sub>os</sub>	Output Offset Voltage	V <sub>IN</sub> = 0V	5		mV
Po	Output Power	THD = 1% (max); f = 1 kHz; $R_L = 8\Omega$	200		mW
		THD = 1% (max); f = 1 kHz; $R_L = 16\Omega$	175		mW
THD+N	Total Harmonic Distortion+Noise	$\begin{split} P_{O} &= 100 \text{ mWrms; } A_{VD} = 2;  R_{L} = 8\Omega; \\ 20  Hz \leq f \leq 20         $	1.5		%
PSRR	Power Supply Rejection Ratio	V <sub>DD</sub> = 2.9V–3.1V	50		dB

Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

**Note 3:** The maximum power dissipation must be derated at elevated temperatures and is dictated by  $T_{JMAX}$ ,  $\theta_{JA}$ , and the ambient temperature  $T_A$ . The maximum allowable power dissipation is  $P_{DMAX} = (T_{JMAX} - T_A)/\theta_{JA}$  or the number given in the Absolute Maximum Ratings, whichever is lower. For the LM4864,  $T_{JMAX} = 150^{\circ}$ C. The typical junction-to-ambient thermal resistance, when board mounted, is 230°C/W for package number MUA08A, 170°C/W for package number M08A and is 107°C/W for package number N08E<sup>\*</sup>.

Note 4: Human body model, 100pF discharged through a  $1.5k\Omega$  resistor.

Note 5: Machine Model, 220pF - 240pF discharged through all pins.

Note 6: Typicals are measured at 25°C and represent the parametric norm.

Note 7: Limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

Note 8: Datasheet min/max specification limits are guaranteed by design, test, or statistical analysis.

Note 9: The quiescent power supply current depends on the offset voltage when a practical load is connected to the amplifier.

Note 10: The MUA08BA package is thermally limited to 595 mW of power dissipation at room temperature. Refering to the Power Dissipation vs Output Power graph in the **Typical Performance Characteristics** section, the power dissipation limitation for the package occurs at 300 mW of output power. This package limitation is based on 25°C ambient temperature and  $\theta_{JA} = 210$ °C. For higher output power possibilities refer to the **Power Dissipation** Section.

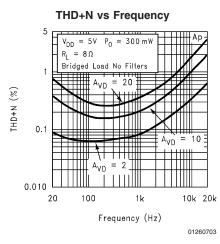
Note 11: The LDA10A package has its exposed-DAP soldered to an exposed 1.2in<sup>2</sup> area of 1oz printed circuit board copper.

\* Not recommended for new designs. Contact NSC Audio Marketing.

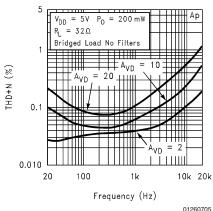
## External Components Description (Figure 1)

Components		Functional Description
1.	R <sub>i</sub>	Inverting input resistance which sets the closed-loop gain in conjunction with $R_F$ . This resistor also forms a high pass filter with $C_i$ at $f_c = 1/(2\pi R_i C_i)$ .
2.	C <sub>i</sub>	Input coupling capacitor which blocks the DC voltage at the amplifier's input terminals. Also creates a highpass filter with $R_i$ at $f_c = 1/(2\pi R_iC_i)$ . Refer to the section, <b>Proper Selection of External Components</b> , for an explanation of how to determine the value of $C_i$ .
3.	R <sub>F</sub>	Feedback resistance which sets the closed-loop gain in conjunction with R <sub>i</sub> .
4.	Cs	Supply bypass capacitor which provides power supply filtering. Refer to the <b>Power Supply Bypassing</b> section for information concerning proper placement and selection of the supply bypass capacitor.
5.	C <sub>B</sub>	Bypass pin capacitor which provides half-supply filtering. Refer to the <b>Proper Selection of External</b> <b>Components</b> for information concerning proper placement and selection of C <sub>B</sub> .

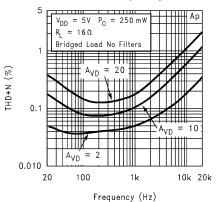
## **Typical Performance Characteristics**



#### **THD+N vs Frequency**

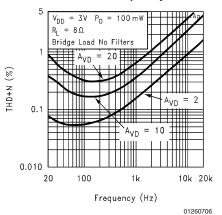


#### **THD+N vs Frequency**



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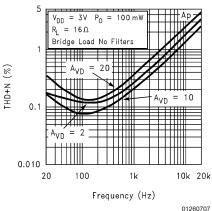
#### THD+N vs Frequency



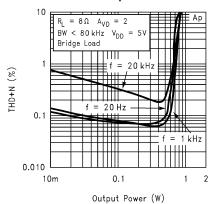
# LM4864

# Typical Performance Characteristics (Continued)



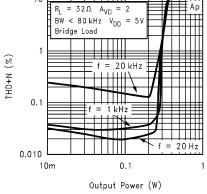


**THD+N vs Output Power** 



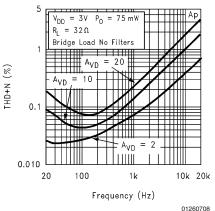
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THD+N vs Output Power

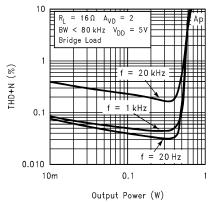


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**THD+N vs Frequency** 

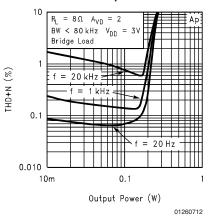


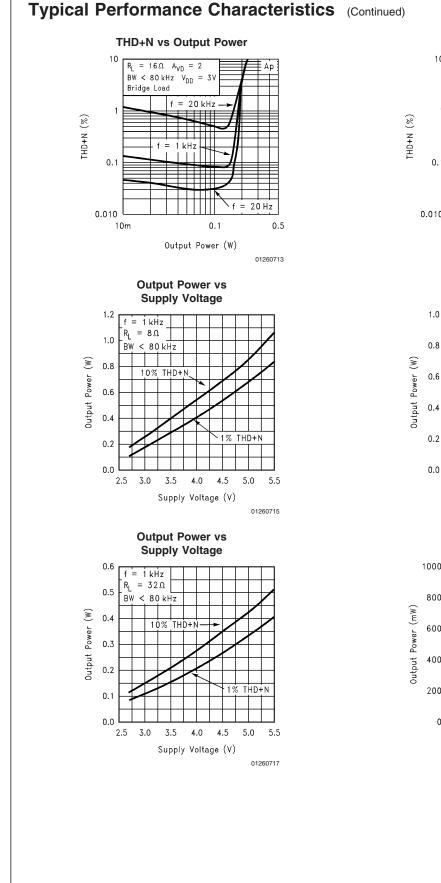
**THD+N vs Output Power** 



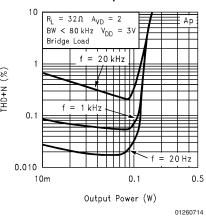
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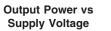
THD+N vs Output Power

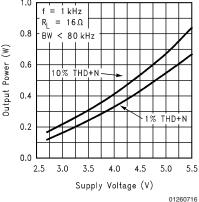




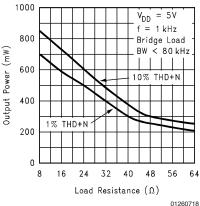
#### THD+N vs Output Power

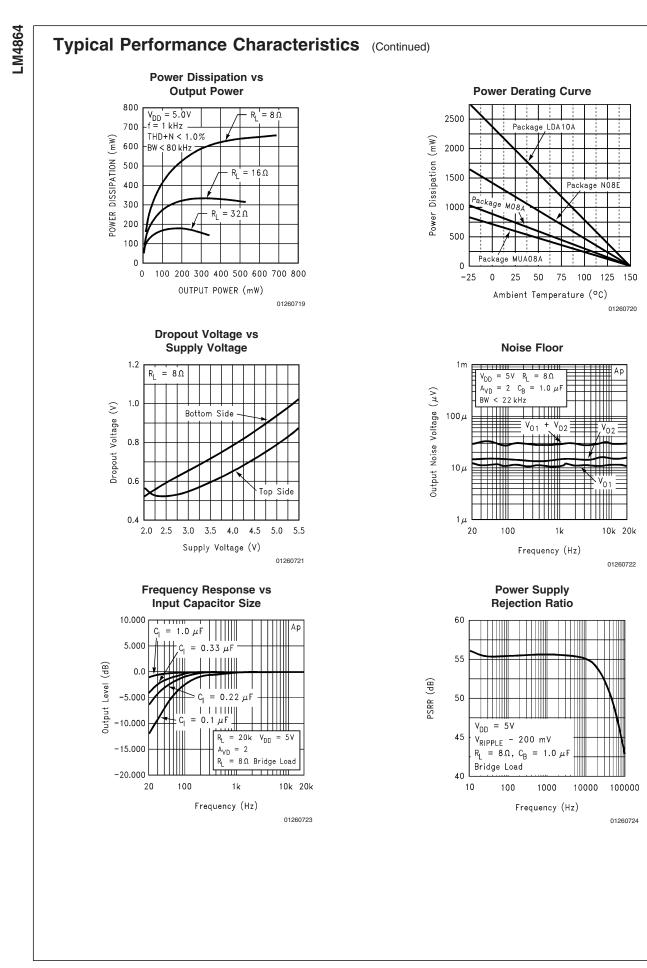


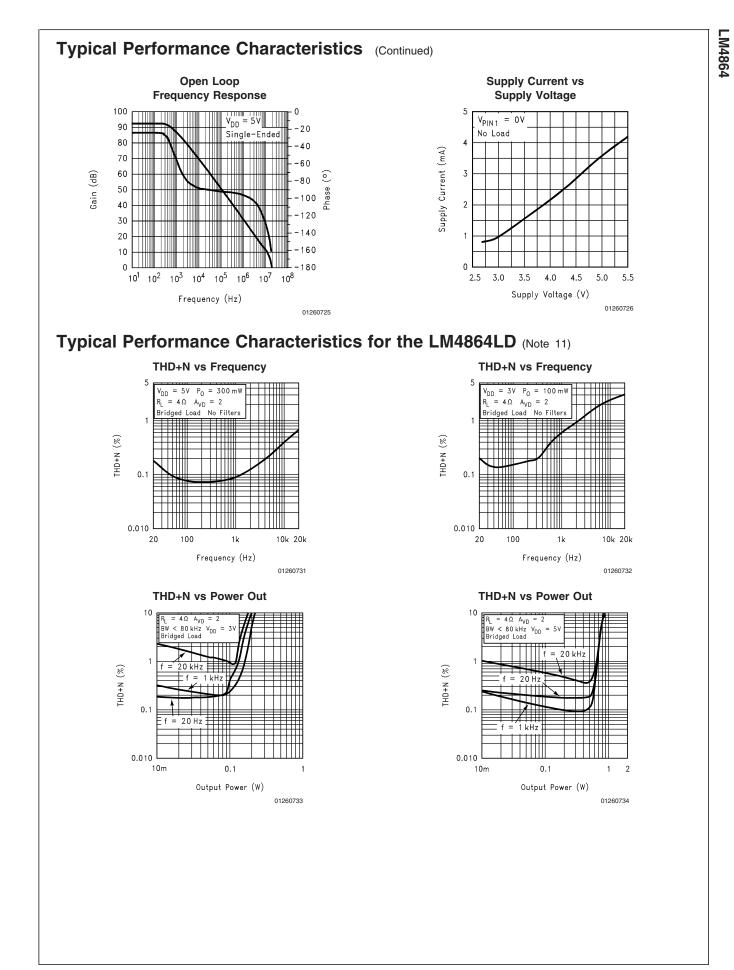




Output Power vs Load Resistance



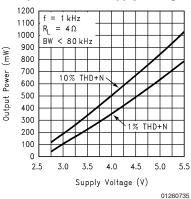




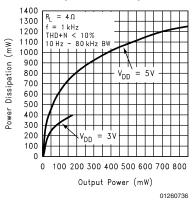


# Typical Performance Characteristics for the LM4864LD (Note 11) (Continued)

#### **Output Power vs Supply Voltage**



**Power Dissipation vs Output Power** 



## **Application Information**

#### BRIDGE CONFIGURATION EXPLANATION

As shown in *Figure 1*, the LM4864 has two operational amplifiers internally, allowing for a few different amplifier configurations. The first amplifier's gain is externally configurable, while the second amplifier is internally fixed in a unity-gain, inverting configuration. The closed-loop gain of the first amplifier is set by selecting the ratio of  $R_F$  to  $R_i$  while the second amplifier's gain is fixed by the two internal  $10k\Omega$  resistors. *Figure 1* shows that the output of amplifier one serves as the input to amplifier two which results in both amplifiers producing signals identical in magnitude, but out of phase  $180^{\circ}$ . Consequently, the differential gain for the IC is

#### $A_{VD} = 2^*(R_F/R_i)$

By driving the load differentially through outputs  $V_{o1}$  and  $V_{o2},$  an amplifier configuration commonly referred to as "bridged mode" is established. Bridged mode operation is different from the classical single-ended amplifier configuration where one side of its load is connected to ground.

A bridge amplifier design has a few distinct advantages over the single-ended configuration, as it provides differential drive to the load, thus doubling output swing for a specified supply voltage. Four times the output power is possible as compared to a single-ended amplifier under the same conditions. This increase in attainable output power assumes that the amplifier is not current limited or clipped. In order to choose an amplifier's closed-loop gain without causing excessive clipping, please refer to the **Audio Power Amplifier Design** section.

A bridge configuration, such as the one used in LM4864, also creates a second advantage over single-ended amplifiers. Since the differential outputs,  $V_{o1}$  and  $V_{o2}$ , are biased at half-supply, no net DC voltage exists across the load. This eliminates the need for an output coupling capacitor which is required in a single supply, single-ended amplifier configuration. If an output coupling capacitor is not used in a single-ended configuration, the half-supply bias across the load would result in both increased internal IC power dissipation as well as permanent loudspeaker damage.

#### POWER DISSIPATION

Power dissipation is a major concern when designing a successful amplifier, whether the amplifier is bridged or single-ended. Equation 1 states the maximum power dissipation point for a bridge amplifier operating at a given supply voltage and driving a specified output load.

 $P_{DMAX} = (V_{DD})^2 / (2\pi^2 R_L)$  Single-Ended (1)

However, a direct consequence of the increased power delivered to the load by a bridge amplifier is an increase in internal power dissipation point for a bridge amplifier operating at the same conditions.

$$P_{DMAX} = 4(V_{DD})^2/(2\pi^2 R_L) \qquad \text{Bridge Mode (2)}$$

Since the LM4864 has two operational amplifiers in one package, the maximum internal power dissipation is 4 times that of a single-ended amplifier. Even with this substantial increase in power dissipation, the LM4864 does not require heatsinking. From Equation 1, assuming a 5V power supply and an  $8\Omega$  load, the maximum power dissipation point is 633 mW. The maximum power dissipation point obtained from Equation 2 must not be greater than the power dissipation that results from Equation 3:

$$P_{DMAX} = (T_{JMAX} - T_A)/\theta_{JA} \qquad (3)$$

For package MUA08A,  $\theta_{JA} = 210^{\circ}$ C/W, for package M08A,  $\theta_{JA} = 170^{\circ}$ C/W, for package N08E,  $\theta_{JA} = 107^{\circ}$ C/W, and for package LDA10A,  $\theta_{JA} = 63^{\circ}$ C/W. T<sub>JMAX</sub> = 150°C for the LM4864. Depending on the ambient temperature,  $T_A$ , of the system surroundings, Equation 3 can be used to find the maximum internal power dissipation supported by the IC packaging. If the result of Equation 2 is greater than that of Equation 3, then either the supply voltage must be decreased, the load impedance increased, the ambient temperature reduced, or the  $\theta_{\mathsf{JA}}$  reduced with heatsinking. In many cases larger traces near the output,  $V_{\text{DD}},$  and GND pins can be used to lower the  $\theta_{JA}$ . The larger areas of copper provide a form of heatsinking allowing a higher power dissipation. For the typical application of a 5V power supply, with an  $8\Omega$  load, the maximum ambient temperature possible without violating the maximum junction temperature is approximately 44°C provided that device operation is around the maximum power dissipation point and assuming surface mount packaging. Internal power dissipation is a function of output power. If typical operation is not around the maximum power dissipation point, the ambient temperature can be increased. Refer to the Typical Performance Characteristics curves for power dissipation information for lower output powers.

# EXPOSED-DAP PACKAGE PCB MOUNTING CONSIDERATION

The LM4864's exposed-dap (die attach paddle) package (LD) provides a low thermal resistance between the die and the PCB to which the part is mounted and soldered. This allows rapid heat transfer from the die to the surrounding PCB copper traces, ground plane, and surrounding air.

The LD package should have its DAP soldered to a copper pad on the PCB. The DAP's PCB copper pad may be connected to a large plane of continuous unbroken copper. This plane forms a thermal mass, heat sink, and radiation area.

Further detailed and specific information concerning PCB layout, fabrication, and mounting an LD (LLP) package is available from National Semiconductor's Package Engineering Group under application note AN1187.

#### POWER SUPPLY BYPASSING

As with any power amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. The capacitor location on both the bypass and power supply pins should be as close to the device as possible. The effect of a larger half supply bypass capacitor is improved PSRR due to increased half-supply stability. Typical applications employ a 5V regulator with 10  $\mu$ F and a 0.1  $\mu$ F bypass capacitors which aid in supply stability, but do not eliminate the need for bypassing the supply nodes of the LM4864. The selection of bypass capacitors, especially C<sub>B</sub>, is thus dependent upon desired PSRR requirements, click and pop performance as explained in the section, **Proper Selection of External Components**, system cost, and size constraints.

#### SHUTDOWN FUNCTION

In order to reduce power consumption while not in use, the LM4864 contains a shutdown pin to externally turn off the amplifier's bias circuitry. This shutdown feature turns the amplifier off when a logic high is placed on the shutdown pin. The trigger point between a logic low and logic high level is typically half supply. It is best to switch between ground and supply to provide maximum device performance. By switching the shutdown pin to  $V_{\rm DD}$ , the LM4864 supply current

## Application Information (Continued)

draw will be minimized in idle mode. While the device will be disabled with shutdown pin voltages less than  $V_{DD}$ , the idle current may be greater than the typical value of 0.7 µA. In either case, the shutdown pin should be tied to a definite voltage to avoid unwanted state changes.

In many applications, a microcontroller or microprocessor output is used to control the shutdown circuitry which provides a quick, smooth transition into shutdown. Another solution is to use a single-pole, single-throw switch in conjunction with an external pull-up resistor. When the switch is closed, the shutdown pin is connected to ground and enables the amplifier. If the switch is open, then the external pull-up resistor will disable the LM4864. This scheme guarantees that the shutdown pin will not float, thus preventing unwanted state changes.

#### PROPER SELECTION OF EXTERNAL COMPONENTS

Proper selection of external components in applications using integrated power amplifiers is critical to optimize device and system performance. While the LM4864 is tolerant to a variety of external component combinations, consideration to component values must be used to maximize overall system quality.

The LM4864 is unity-gain stable, giving a designer maximum system flexibility. The LM4864 should be used in low gain configurations to minimize THD+N values, and maximize the signal to noise ratio. Low gain configurations require large input signals to obtain a given output power. Input signals equal to or greater than 1 Vrms are available from sources such as audio codecs. Please refer to the section, Audio Power Amplifier Design, for a more complete explanation of proper gain selection.

Besides gain, one of the major considerations is the closedloop bandwidth of the amplifier. To a large extent, the bandwidth is dictated by the choice of external components shown in Figure 1. The input coupling capacitor, C<sub>i</sub>, forms a first order high pass filter which limits low frequency response. This value should be chosen based on needed frequency response for a few distinct reasons.

#### Selection of Input Capacitor Size

Large input capacitors are both expensive and space hungry for portable designs. Clearly, a certain sized capacitor is needed to couple in low frequencies without severe attenuation. But in many cases the speakers used in portable systems, whether internal or external, have little ability to reproduce signals below 150 Hz. In this case using a large input capacitor may not increase system performance.

In addition to system cost and size, click and pop performance is effected by the size of the input coupling capacitor, C<sub>i</sub>. A larger input coupling capacitor requires more charge to reach its quiescent DC voltage (nominally  $\frac{1}{2}$  V<sub>DD</sub>). This charge comes from the output via the feedback and is apt to create pops upon device enable. Thus, by minimizing the capacitor size based on necessary low frequency response, turn-on pops can be minimized.

Besides minimizing the input capacitor size, careful consideration should be paid to the bypass capacitor value. Bypass capacitor, C<sub>B</sub>, is the most critical component to minimize turn-on pops since it determines how fast the LM4864 turns on. The slower the LM4864's outputs ramp to their quiescent DC voltage (nominally  $\frac{1}{2}$  V<sub>DD</sub>), the smaller the turn-on pop. Choosing C<sub>B</sub> equal to 1.0 µF along with a small value of C<sub>i</sub> (in the range of 0.1  $\mu$ F to 0.39  $\mu$ F), should produce a click-

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less and popless shutdown function. While the device will function properly, (no oscillations or motorboating), with CB equal to 0.1 µF, the device will be much more susceptible to turn-on clicks and pops. Thus, a value of C<sub>B</sub> equal to 1.0 µF or larger is recommended in all but the most cost sensitive designs.

#### AUDIO POWER AMPLIFIER DESIGN

#### Design a 300 mW/8Ω Audio Amplifier

Given:	
Power Output	300 mWrms
Load Impedance	8Ω
Input Level	1 Vrms
Input Impedance	20 kΩ
Bandwidth	100 Hz–20 kHz ± 0.25 dB

A designer must first determine the minimum supply rail to obtain the specified output power. By extrapolating from the Output Power vs Supply Voltage graphs in the Typical Performance Characteristics section, the supply rail can be easily found. A second way to determine the minimum supply rail is to calculate the required  $V_{\rm opeak}$  using Equation 4 and add the dropout voltage. Using this method, the minimum supply voltage would be ( $V_{\rm opeak}$  + (2\*V\_{OD})), where  $V_{\rm OD}$  is extrapolated from the Dropout Voltage vs Supply Voltage curve in the Typical Performance Characteristics section.

$$V_{opeak} = \sqrt{(2R_LP_O)}$$
(4)

Using the Output Power vs Supply Voltage graph for an  $8\Omega$ load, the minimum supply rail is 3.5V. But since 5V is a standard supply voltage in most applications, it is chosen for the supply rail. Extra supply voltage creates headroom that allows the LM4864 to reproduce peaks in excess of 500 mW without producing audible distortion. At this time, the designer must make sure that the power supply choice along with the output impedance does not violate the conditions explained in the Power Dissipation section.

Once the power dissipation equations have been addressed, the required differential gain can be determined from Equation 5.

$$A_{VD} \ge \sqrt{(PoR_L)} / (V_{IN}) = V_{orms} / V_{inrms}$$

$$R_F / R_i = A_{VD} / 2 \qquad (6)$$

From Equation 5, the minimum  $A_{VD}$  is 1.55; use  $A_{VD}$  = 2. Since the desired input impedance was 20 k $\Omega$ , and with a A<sub>VD</sub> of 2, a ratio of 1:1 of R<sub>F</sub> to R<sub>i</sub> results in an allocation of  $R_i = R_F = 20 \text{ k}\Omega$ . The final design step is to address the bandwidth requirements which must be stated as a pair of -3 dB frequency points. Five times away from a pole gives 0.17 dB down from passband response which is better than the required ±0.25 dB specified.

As stated in the External Components section, Ri in conjunction with C<sub>i</sub> create a highpass filter.

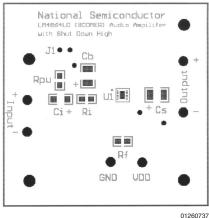
$$C_{i} \geq \frac{1}{2\pi \; R_{i} \, f_{c}}$$

 $C_i \ge 1/(2\pi^*20 \text{ k}\Omega^*20 \text{ Hz}) = 0.397 \mu\text{F};$  use 0.39  $\mu\text{F}$ 

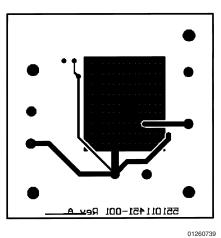
## Application Information (Continued)

The high frequency pole is determined by the product of the desired high frequency pole,  $f_{\rm H}$ , and the differential gain,  $A_{\rm VD}$ . With a  $A_{\rm VD}$  = 2 and  $f_{\rm H}$  = 100 kHz, the resulting GBWP

### LM4864LD DEMO BOARD ARTWORK

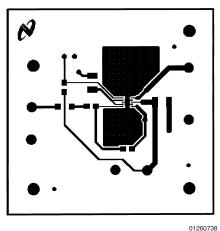


Silk Screen View of LM4864LD



Bottom Layer of LM4864LD

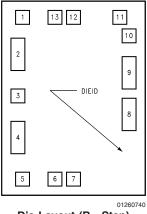
= 100 kHz which is much smaller than the LM4864 GBWP of 18 MHz. This figure displays that if a designer has a need to design an amplifier with a higher differential gain, the LM4864 can still be used without running into bandwidth problems.



Top Layer of LM4864LD



## LM4864 MDC MWC 725MW Audio Power Amplifier With Shutdown Mode



Die Layout (B - Step)

## **DIE/WAFER CHARACTERISTICS**

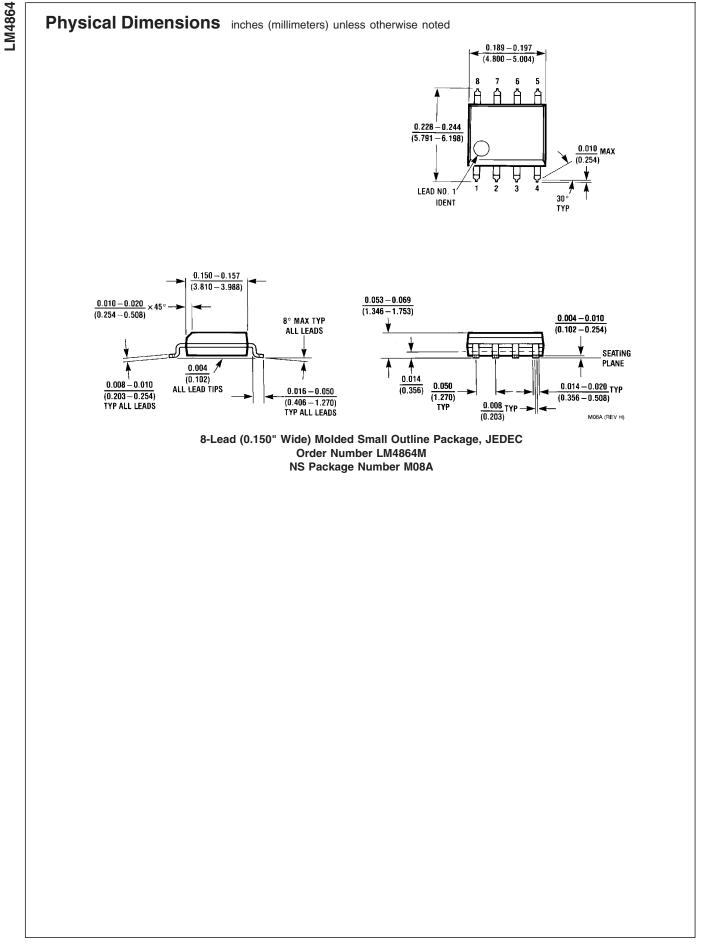
	Fabrication Attri	butes			General Die Int	formation		
Physical Die Ider	Physical Die Identification LM4862B		Bond Pad Opening Size (min)		i) 86µi	86µm x 86µm		
Die Step		В		Bond Pa	d Metalization	ALU	ALUMINUM	
	Physical Attrib	utes		Passivati	ion	NITI	NITRIDE	
Wafer Diameter		150mm		Back Sid	le Metal	Bare	Bare Back	
Dise Size (Drawr	ו)	1283µm x	952µm	Back Sid	le Connection	GNE	C	
		51mils x 3	7mils					
Thickness		406µm No	ominal					
Min Pitch		117µm No	minal					
Special Assem	bly Requirements:							
Note: Actual di	e size is rounded to t	he nearest micro	n.					
	C	ie Bond Pad Coor	dinate Loc	ations (B -	Step)			
	(Referenced	d to die center, coo	ordinates ir	η μm) NC =	No Connection			
SIGNAL NAME PAD# NUMBER		X/Y COC	X/Y COORDINATES		PAD SIZE			
		Х		Y	Х		Y	
BYPASS	1	-322	5	623	86	Х	86	
GND	2	-359	2	259	86	х	188	
INPUT +	3	-359		5	86	х	86	
GND	4	-359	-2	259	86	х	188	
NC	5	-323	-5	523	86	х	86	
INPUT -	6	-109	-5	523	86	х	86	
VOUT 1	7	8	-5	523	86	х	86	
VDD	8	358	-	78	86	х	188	
GND	9	358	1	41	86	х	188	
NC	10	359	4	06	86	х	86	
NC	11	323	5	523	86	х	86	
VOUT 2	12	8	5	523	86	х	86	
SHUTDOWN	13	-109	5	623	86	х	86	

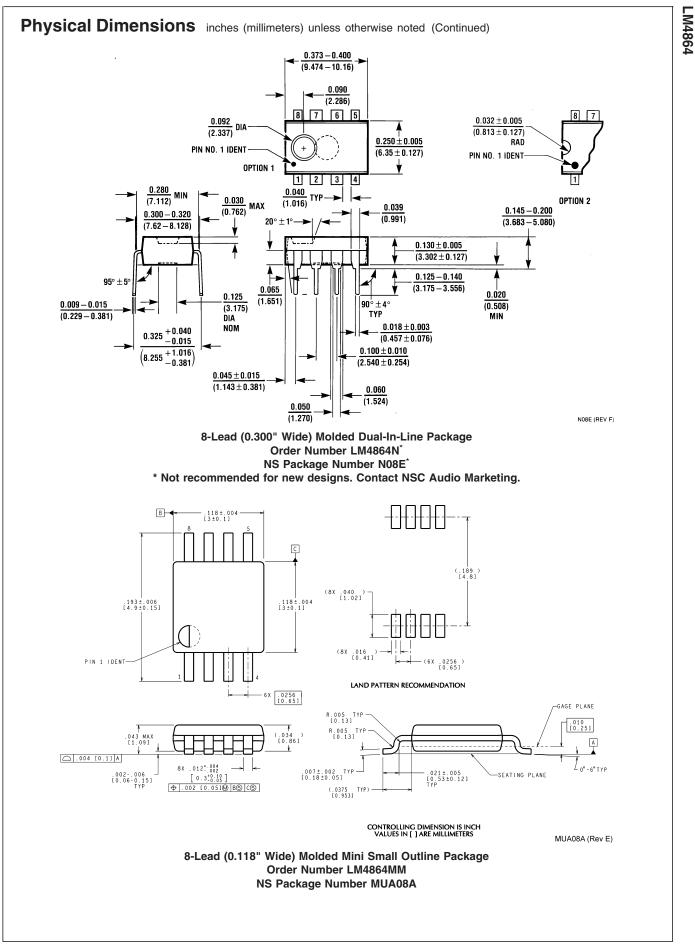
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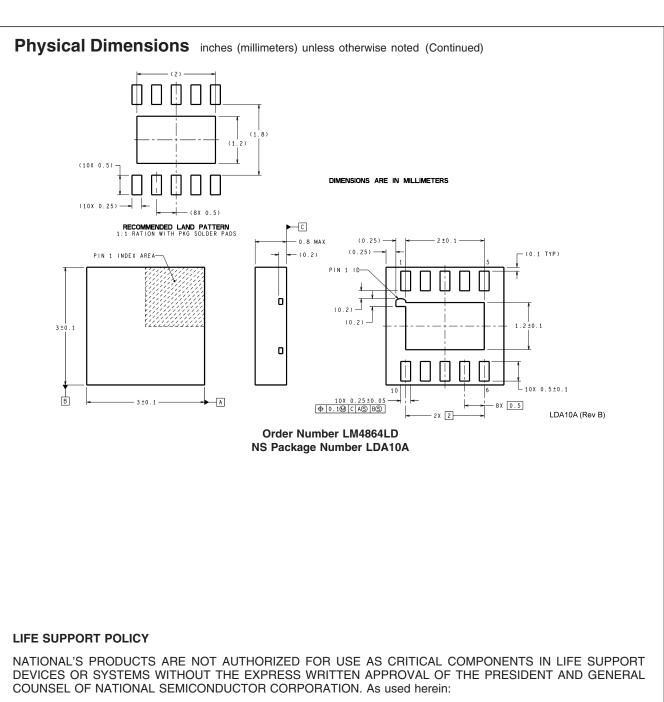
LM4864

## LM4864 MDC MWC 725MW Audio Power Amplifier With Shutdown Mode (Continued)

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- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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